Ordering information

Order reference	Voltage (V)	Package	Part marking	Status	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXCL250H5TA	2.5	SC70-5	L25A	Active	7	8	3000
ZXCL260H5TA	2.6	SC70-5	L26A	Active	7	8	3000
ZXCL280H5TA	2.8	SC70-5	L28A	Active	7	8	3000
ZXCL300H5TA	3.0	SC70-5	L30A	Active	7	8	3000
ZXCL330H5TA	3.3	SC70-5	L33A	Active	7	8	3000
ZXCL400H5TA	4.0	SC70-5	L40A	Obsolete	7	8	3000
ZXCL5213V25H5TA	2.5	SC70-5	L25C	Active	7	8	3000
ZXCL5213V26H5TA	2.6	SC70-5	L26C	Active	7	8	3000
ZXCL5213V28H5TA	2.8	SC70-5	L28C	Active	7	8	3000
ZXCL5213V30H5TA	3.0	SC70-5	L30C	Active	7	8	3000
ZXCL5213V33H5TA	3.3	SC70-5	L33C	Active	7	8	3000
ZXCL5213V40H5TA	4.0	SC70-5	L40C	Not rec. for new designs	7	8	3000
ZXCL250E5TA	2.5	SOT23-5	L25B	Active	7	8	3000
ZXCL260E5TA	2.6	SOT23-5	L26B	Active	7	8	3000
ZXCL280E5TA	2.8	SOT23-5	L28B	Active	7	8	3000
ZXCL300E5TA	3.0	SOT23-5	L30B	Active	7	8	3000
ZXCL330E5TA	3.3	SOT23-5	L33B	Active	7	8	3000
ZXCL400E5TA	4.0	SOT23-5	L40B	Obsolete	7	8	3000

Absolute maximum rating

Terminal Voltage with respect to GND Output short circuit duration Infinite

 V_{IN} -0.3V to 7.0V Continuous power dissipation Internally limited

 E_{N} -0.3V to 10V Operating temperature range -40°C to +85°C V_{O} -0.3V to 5.5V Storage temperature range -55°C to +125°C

Package power dissipation (T_A=25°C)

SC70-5 300mW (Note 1) SOT23-5 450mW (Note 1)

Stresses beyond those listed under "Absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum conditions for extended periods may affect device reliability.

Recommended operating conditions

Symbol	Parameter	Min	Max	Units
V _{IN}	Input voltage range	2.0*	5.5	V
V _{ENH}	Enable pin logic level High pin	2.2	10	V
V _{ENL}	Enable pin logic level Low pin	0	0.8	V
T _A	Ambient temperature range	-40	85	°C

^{*} Output voltage will start to rise when V_{IN} exceeds a value or approximately 1.3V. For normal operation, $V_{IN(min)} > V_{OUT(nom)} + 0.5V$.

Pin description

Symbol	Parameter
V _{IN}	Supply voltage
G _{ND}	Ground
E _N	Active HIGH enable input. TTL/CMOS logic compatible. Connect to $V_{\rm IN}$ or logic high for normal operation
N/C	No connection
Vo	Regulator output

Electrical characteristics

 $V_{IN} = V_O = 0.5V$, all values at $T_A = 25$ °C (Unless otherwise stated)

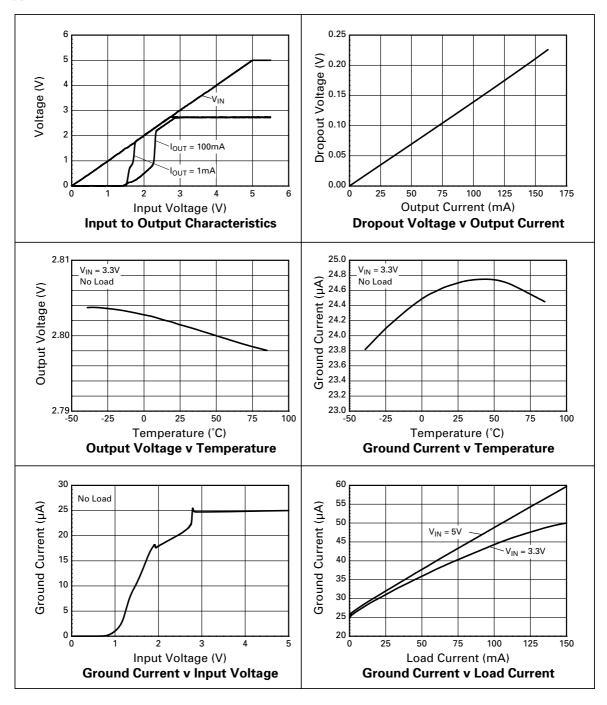
Symbol	Parameter	Conditions			Limits		
				Min.	Тур.	Max.	
Vo	Output voltage	I _O =1mA		-2%		+2%	V
		I _O =100mA					
		$V_{O} + 0.5V < V_{O}$	/ _{IN} < V _{IN} max	-3%		+3%	V
$\Delta V_{O}/\Delta T$	Output voltage temperature coefficient				-15		ppm/°C
I _{O(Max)}	Output current			150			mA
		XCL250/52	13V25 only	100			
I _{OLIM}	Over current limit			160		800	mA
		XCL250/52	13V25 only	105	230	750	
I _O	Ground pin	No Load			25	50	μΑ
	current	I _O =150mA			50	120	μΑ
		I _O =100mA			40	100	μΑ
V_{DO}	Dropout voltage note 3	I _O =10mA	All variants		15		mV
		I _O =50mA			85		mV
		I _O =100mA	ZXCL250 / 5213V25		163	325	mV
		I _O =100mA	ZXCL260 / 5213V26		155	310	mV
		I _O =100mA	ZXCL280 / 5213V28		140	280	mV
		I _O =100mA	ZXCL300 / 5213V30		140	280	mV
		I _O =100mA	ZXCL330 / 5213V33		140	280	mV
		I _O =100mA	ZXCL400 / 5213V40		140	280	mV
ΔV_{LNR}	Line regulation	$V_{IN}=(V_O+0.$	5V) to 5.5V, I _O =1mA		0.02	0.1	%/V
ΔV_{LDR}	Load regulation	I _O =1mA to	100mA		0.01	0.04	%/mA
E _N	Output noise voltage	f=10Hz to 1	00kHz, C _O =10μF		50		μV_{RMS}
V _{ENHS}	Enable pin hysteresis				150		mV
I _{EN}	Enable pin input current	V _{EN} =5.5V				100	nV
I _{OSD}	Shutdown supply current	V _{EN} =0V				1	μΑ
T _{SD}	Thermal shutdown temperature			125		165	°C

Device testing is performed at $T_A=25$ °C. Device thermal performance is guaranteed by design.

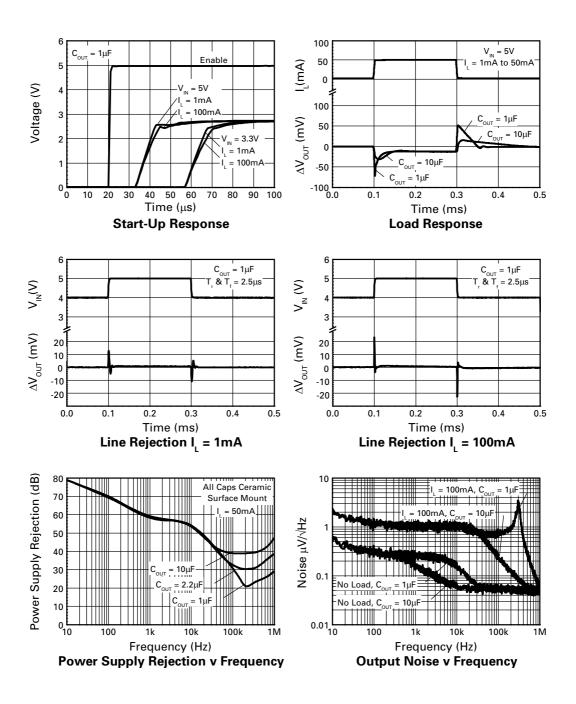
Note1: Maximum power dissipation is calculated assuming the device is mounted on a PCB measuring 2 inches square Note2:Output voltage will start to rise when V_{IN} exceeds a value or approximately 1.3V. For normal operation,

 $V_{IN(min)} > V_{OUT(nom)} + 0.5V$. Note3:Dropout voltage is defined as the difference between V_{IN} and V_{O} , when V_{O} has dropped 100mV below its nominal value. Nominal value of V_{O} is defined at V_{IN} = V_{O} +0.5V.

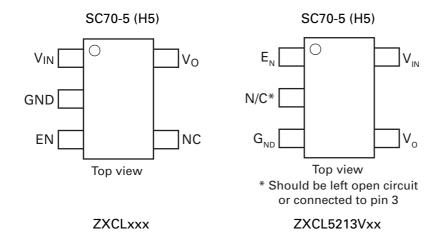
Typical characteristics (ZXCL280 / 5213 shown)



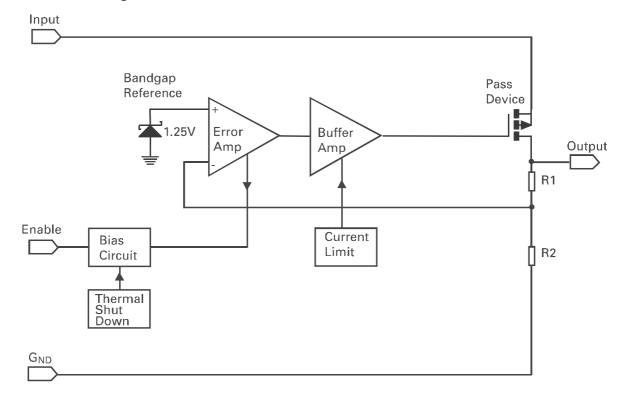
Typical characteristics



Connection diagrams



Schematic diagram

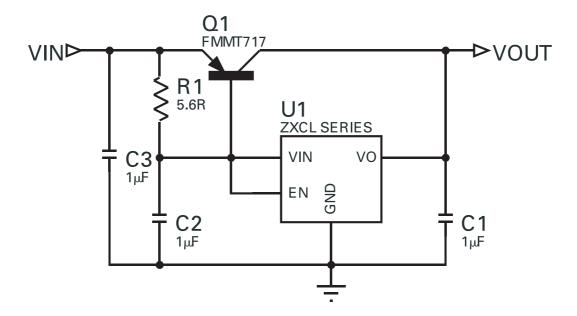


Input to Output Diode

In common with many other LDO regulators, the ZXCL device has an inherent diode associated with the output series pass transistor. This diode has its anode connected to the output and its cathode to the input. The internal diode is normally reverse biased, but will conduct if the output is forced above the input by more than a VBE (approximately 0.6V). Current will then flow from V_{out} to V_{in}. For safe operation, the maximum current in this diode should be limited to 5mA continuous and 30mA peak. An external schottky diode may be used to provide protection when this condition cannot be satisfied.

Increased Output current

Any ZXCL series device may be used in conjunction with an external PNP transistor to boost the output current capability. In the application circuit shown below, a FMMT717 device is employed as the external pass element. This SOT23 device can supply up to 2.5A maximum current subject to the thermal dissipation limits of the package (625mW). Alternative devices may be used to supply higher levels of current. Note that with this arrangement, the dropout voltage will be increased by the $\rm V_{BE}$ drop of the external device. Also, care should be taken to protect the pass transistor in the event of excessive output current.



Scheme to boost output current to 2A

Applications information

Enable control

A TTL compatible input is provided to allow the regulator to be shut down. A low voltage on the Enable pin puts the device into shutdown mode. In this mode the regulator circuit is switched off and the quiescent current reduces to virtually zero (typically less than 10nA) for input voltages above the minimum operating threshold of the device. A high voltage on the Enable pin ensures normal operation.

The Enable pin can be connected to V_{IN} or driven from an independent source of up to 10V maximum. (e.g. CMOS logic) for normal operation. There is no clamp diode from the Enable pin to V_{IN} , so the V_{IN} pin may be at any voltage within its operating range irrespective of the voltage on the Enable pin. However input voltage rise time should be kept below 5ms to ensure consistent start-up response.

Current Limit

The ZXCL devices include a current limit circuit which restricts the maximum output current flow to typically 230mA. Practically the range of over-current should be considered as minimum 160mA to maximum 800mA. The device's robust design means that an output short circuit to any voltage between ground and V_{OUT} can be tolerated for an indefinite period.

Thermal Overload

Thermal overload protection is included on chip. When the device junction temperature exceeds a minimum 125°C the device will shut down. The sense circuit will re-activate the output as the device cools. It will then cycle until the overload is removed. The thermal overload protection will be activated when high load currents or high input to output voltage differentials cause excess dissipation in the device.

Start up delay

A small amount of hysteresis is provided on the Enable pin to ensure clean switching. This feature can be used to introduce a start up delay if required. Addition of a simple RC network on the Enable pin provides this function. The following diagram illustrates this circuit connection. The equation provided enables calculation of the delay period.

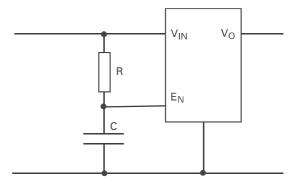


Figure 1 Circuit Connection

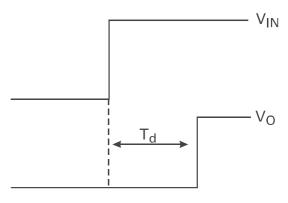


Figure 2 Start up delay (T_d)

$$T_{d(NOM)} = RCIn \left(\frac{V_{IN}}{V_{IN} - 1.5} \right)$$

Calculation of start up delay as above

Applications information (Cont)

Power dissipation

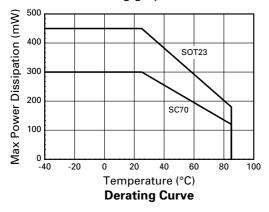
The maximum allowable power dissipation of the device for normal operation (P_{max}), is a function of the package junction to ambient thermal resistance (θ_{ja}), maximum junction temperature (T_{jmax}), and ambient temperature (T_{amb}), according to the expression:

$$P_{max} = (Tj_{max} - T_{amb}) / \theta_{ja}$$

The maximum output current (I_{max}) at a given value of Input voltage (V_{OLIT}) is then given by

$$I_{max} = P_{max} / (V_{IN} - V_{OUT})$$

The value of qja is strongly dependent upon the type of PC board used. Using the SC70 package it will range from approximately 280°C/W for a multi-layer board to around 450°C/W for a single sided board. It will range from 180°C/W to 300°C/W for the SOT23-5 package. To avoid entering the thermal shutdo wn state, Tjmax should be assumed to be 125°C and Imax less than the over-current limit,(I_{OLIM}). Power derating for the SC70 and SOT23-5 packages is shown in the following graph.



Capacitor selection and regulator stability

The device is designed to operate with all types of output capacitor, including tantalum and low ESR ceramic. For stability over the full operating range from no load to maximum load, an output capacitor with a minimum value of $1\mu F$ is recommended, although this can be increased without limit to improve load transient performance. Higher values of output capacitor will also reduce output noise. Capacitors with ESR less than 0.5V are recommended for best results.

The dielectric of the ceramic capacitance is an important consideration for the ZXCL Series operation over temperature. Zetex recommends minimum dielectric specification of X7R for the input and output capacitors. For example a ceramic capacitor with X7R dielectric will lose 20% of its capacitance over a -40°C to 85°C temperature range, whereas a capacitor with a Y5V dielectric loses 80% of its capacitance at -40°C and 75% at 85°C.

An input capacitor of $1\mu F$ (ceramic or tantalum) is recommended to filter supply noise at the device input and will improve ripple rejection.

The input and output capacitors should be positioned close to the device, and a ground plane board layout should be used to minimise the effects of parasitic track resistance.

Dropout voltage

The output pass transistor is a large PMOS device, which acts like a resistor when the regulator enters the dropout region. The dropout voltage is therefore proportional to output current as shown in the typical characteristics.

Ground current

The use of a PMOS device ensures a low value of ground current under all conditions including dropout, start-up and maximum load.

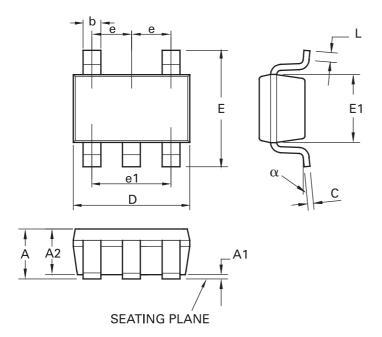
Power supply rejection and load transient response

Line and Load transient response graphs are shown in the typical characteristics.

These show both the DC and dynamic shift in the output voltage with step changes of input voltage and load current, and how this is affected by the output capacitor.

If improved transient response is required, then an output capacitor with lower ESR value should be used. Larger capacitors will reduce over/undershoot, but will increase the settling time. Best results are obtained using a ground plane layout to minimise board parasitics.

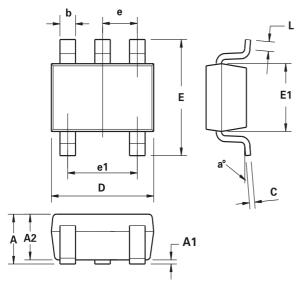
S70-5 Package outline



Dim.	Millin	neters	Inc	hes	Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
Α	0.80	1.10	0.0315	0.0433	Е	2.10	BSC	0.082	6 BSC
A1	-	0.10	-	0.0039	E1	1.25	BSC	0.049	2 BSC
A2	0.80	1.00	0.0315	0.0039	е	0.65	BSC	0.025	5 BSC
b	0.15	0.30	0.006	0.0118	e1	1.30	BSC	0.051	1 BSC
С	0.08	0.25	0.0031	0.0098	L	0.26	0.46	0.010	0.018
D	2.00	BSC	0.078	7 BSC	α	0°	8°	0°	8°

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

SOT23-5 Package outline



DIM	Millimeters		Inc	hes
	Min.	Max.	Min.	Max.
А	0.90	1.45	0.0354	0.0570
A1	0.00	0.15	0.00	0.0059
A2	0.90	1.30	0.0354	0.0511
b	0.20	0.50	0.0078	0.0196
С	0.09	0.26	0.0035	0.0102
D	2.70	3.10	0.1062	0.1220
E	2.20	3.20	0.0866	0.1181
E1	1.30	1.80	0.0511	0.0708
е	0.95	0.95 REF		4 REF
e1	1.90	1.90 REF		8 REF
L	0.10	0.60	0.0039	0.0236
a°	0°	30°	0°	30°

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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